

## IR Receiver Modules for Remote Control Systems



16672

### MECHANICAL DATA

#### Pinning

1 = OUT, 2 =  $V_S$ , 3 = GND

### FEATURES

- Low supply current
- Photo detector and preamplifier in one package
- Internal filter for PCM frequency
- Improved shielding against EMI
- Supply voltage: 2.7 V to 5.5 V
- Improved immunity against ambient light
- Insensitive to supply voltage ripple and noise
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC



### DESCRIPTION

The TSOP21.. series are miniaturized receivers for infrared remote control systems. A PIN diode and a preamplifier are assembled on a lead frame, the epoxy package acts as an IR filter.

The demodulated output signal can directly be decoded by a microprocessor. The main benefit of the TSOP21.. is the compatibility to all IR remote control data formats.

This component has not been qualified according to automotive specifications.

### PARTS TABLE

CARRIER FREQUENCY	SHORT BURSTS AND HIGH DATA RATES (AGC1)
30 kHz	TSOP2130
33 kHz	TSOP2133
36 kHz	TSOP2136
36.7 kHz	TSOP2137
38 kHz	TSOP2138
40 kHz	TSOP2140
56 kHz	TSOP2156

### BLOCK DIAGRAM



### APPLICATION CIRCUIT



The external components  $R_1$  and  $C_1$  are optional to improve the robustness against electrical overstress (typical values are  $R_1 = 100 \Omega$ ,  $C_1 = 0.1 \mu F$ ). The output voltage  $V_O$  should not be pulled down to a level below 1 V by the external circuit. The capacitive load at the output should be less than 2 nF.



ABSOLUTE MAXIMUM RATINGS (1)				
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
Supply voltage (pin 2)		$V_S$	- 0.3 to + 6.0	V
Supply current (pin 2)		$I_S$	5	mA
Output voltage (pin 1)		$V_O$	- 0.3 to 5.5	V
Voltage at output to supply		$V_S - V_O$	- 0.3 to ( $V_S + 0.3$ )	V
Output current (pin 1)		$I_O$	5	mA
Junction temperature		$T_j$	100	°C
Storage temperature range		$T_{stg}$	- 25 to + 85	°C
Operating temperature range		$T_{amb}$	- 25 to + 85	°C
Power consumption	$T_{amb} \leq 85 \text{ °C}$	$P_{tot}$	10	mW
Soldering temperature	$t \leq 10 \text{ s, 1 mm from case}$	$T_{sd}$	260	°C

**Note**

(1) Stresses beyond those listed under “Absolute Maximum Ratings” may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect the device reliability.

ELECTRICAL AND OPTICAL CHARACTERISTICS (1)						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Supply current (pin 2)	$E_v = 0, V_S = 5 \text{ V}$	$I_{SD}$	0.65	0.85	1.05	mA
	$E_v = 40 \text{ klx, sunlight}$	$I_{SH}$		0.95		mA
Supply voltage		$V_S$	2.7		5.5	V
Transmission distance	$E_v = 0$ , test signal see fig. 1, IR diode TSAL6200, $I_F = 400 \text{ mA}$	$d$		45		m
Output voltage low (pin 1)	$I_{OSL} = 0.5 \text{ mA, } E_e = 0.7 \text{ mW/m}^2$ , test signal see fig. 1	$V_{OSL}$			100	mV
Minimum irradiance	Pulse width tolerance: $t_{pi} - 5/f_0 < t_{po} < t_{pi} + 6/f_0$ , test signal see fig. 1	$E_{e \text{ min.}}$		0.17	0.35	$\text{mW/m}^2$
Maximum irradiance	$t_{pi} - 5/f_0 < t_{po} < t_{pi} + 6/f_0$ , test signal see fig. 1	$E_{e \text{ max.}}$	30			$\text{W/m}^2$
Directivity	Angle of half transmission distance	$\phi_{1/2}$		$\pm 45$		deg

**Note**

(1)  $T_{amb} = 25 \text{ °C}$ , unless otherwise specified

**TYPICAL CHARACTERISTICS**

$T_{amb} = 25 \text{ °C}$ , unless otherwise specified

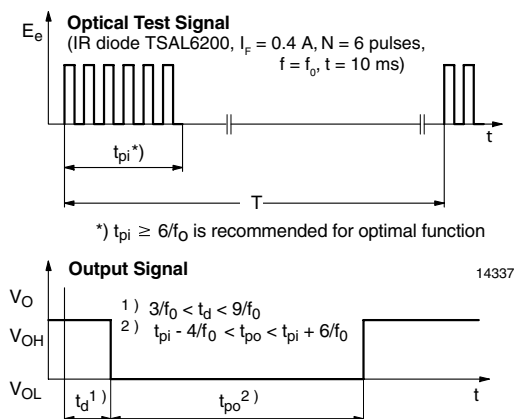


Fig. 1 - Output Active Low



Fig. 2 - Pulse Length and Sensitivity in Dark Ambient

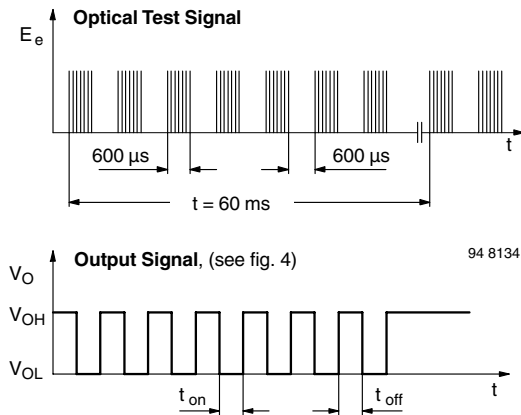


Fig. 3 - Output Function

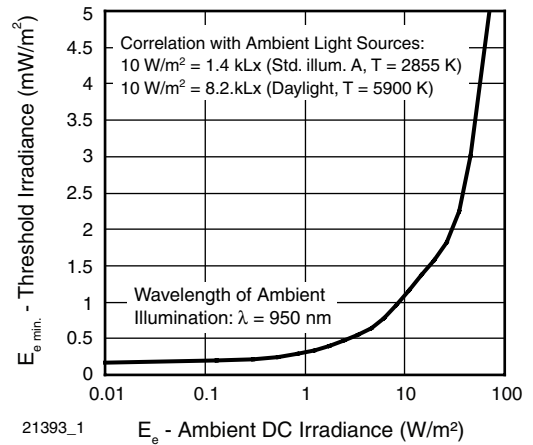


Fig. 6 - Sensitivity in Bright Ambient

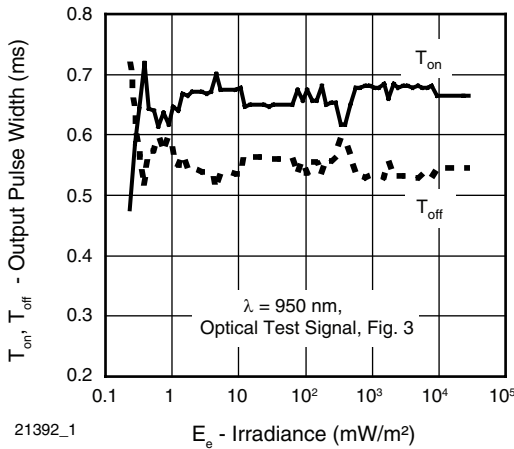


Fig. 4 - Output Pulse Diagram

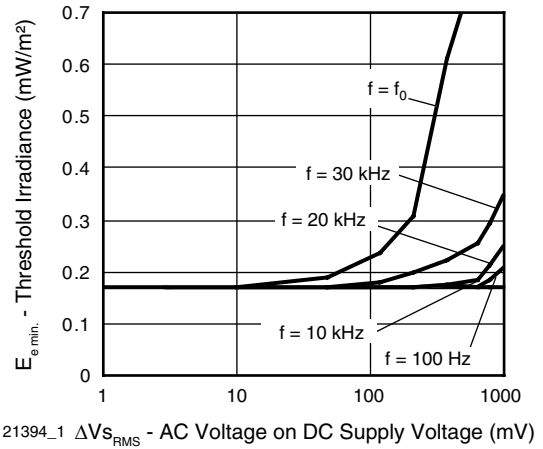


Fig. 7 - Sensitivity vs. Supply Voltage Disturbances

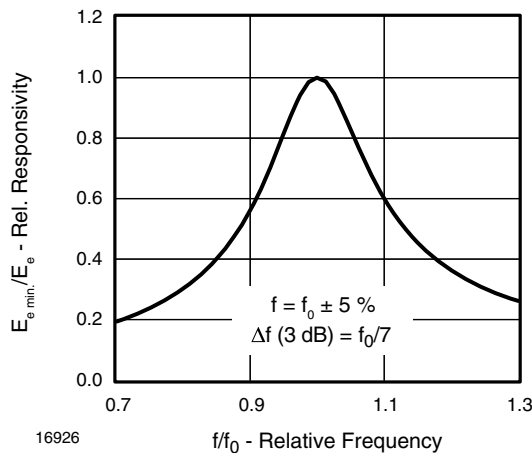


Fig. 5 - Frequency Dependence of Responsivity



Fig. 8 - Sensitivity vs. Electric Field Disturbances



21396\_1 Burst Length (number of cycles/burst)  
Fig. 9 - Max. Envelope Duty Cycle vs. Burst Length



96 12223p2 d<sub>rel</sub> - Relative Transmission Distance  
Fig. 12 - Horizontal Directivity



21397\_1 T<sub>amb</sub> - Ambient Temperature (°C)  
Fig. 10 - Sensitivity vs. Ambient Temperature



21398\_1 V<sub>s</sub> - Supply Voltage (V)  
Fig. 13 - Sensitivity vs. Supply Voltage



16919 λ - Wavelength (nm)  
Fig. 11 - Relative Spectral Sensitivity vs. Wavelength

### SUITABLE DATA FORMAT

The TSOP21.. series is designed to suppress spurious output pulses due to noise or disturbance signals. Data and disturbance signals can be distinguished by the devices according to carrier frequency, burst length and envelope duty cycle. The data signal should be close to the band-pass center frequency (e.g. 38 kHz) and fulfill the conditions in the table below.

When a data signal is applied to the TSOP21.. in the presence of a disturbance signal, the sensitivity of the receiver is reduced to insure that no spurious pulses are present at the output. Some examples of disturbance signals which are suppressed are:

- DC light (e.g. from tungsten bulb or sunlight)
- Continuous signals at any frequency
- Modulated IR signals from common fluorescent lamps (example of noise pattern is shown in figure 14)



Fig. 14 - IR Signal from Fluorescent Lamp with Low Modulation

	TSOP21..
Minimum burst length	6 cycles/burst
After each burst of length a minimum gap time is required of	6 to 70 cycles ≥ 10 cycles
For bursts greater than a minimum gap time in the data stream is needed of	70 cycles > 1.1 x burst length
Maximum number of continuous short bursts/second	2000
Compatible to NEC code	yes
Compatible to RC5/RC6 code	yes
Compatible to RCMM code	yes
Compatible to RECS-80 code	yes
Compatible to r-Step and r-Map data format	yes
Compatible to XMP data format	yes
Suppression of interference from fluorescent lamps	Most common disturbance signals are suppressed

#### Note

For data formats with long bursts (10 carrier cycles or longer) we recommend the TSOP22.. because of the better noise suppression.

# New TSOP21..

Vishay Semiconductors

IR Receiver Modules for  
Remote Control Systems



## PACKAGE DIMENSIONS in millimeters





**OZONE DEPLETING SUBSTANCES POLICY STATEMENT**

It is the policy of Vishay Semiconductor GmbH to

1. Meet all present and future national and international statutory requirements.
2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

Vishay Semiconductor GmbH has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively.
2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA.
3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

Vishay Semiconductor GmbH can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

We reserve the right to make changes to improve technical design  
and may do so without further notice.

Parameters can vary in different applications. All operating parameters must be validated for each customer application by the customer. Should the buyer use Vishay Semiconductors products for any unintended or unauthorized application, the buyer shall indemnify Vishay Semiconductors against all claims, costs, damages, and expenses, arising out of, directly or indirectly, any claim of personal damage, injury or death associated with such unintended or unauthorized use.

Vishay Semiconductor GmbH, P.O.B. 3535, D-74025 Heilbronn, Germany



## Disclaimer

All product specifications and data are subject to change without notice.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained herein or in any other disclosure relating to any product.

Vishay disclaims any and all liability arising out of the use or application of any product described herein or of any information provided herein to the maximum extent permitted by law. The product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein, which apply to these products.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay.

The products shown herein are not designed for use in medical, life-saving, or life-sustaining applications unless otherwise expressly indicated. Customers using or selling Vishay products not expressly indicated for use in such applications do so entirely at their own risk and agree to fully indemnify Vishay for any damages arising or resulting from such use or sale. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

Product names and markings noted herein may be trademarks of their respective owners.



## Данный компонент на территории Российской Федерации

### Вы можете приобрести в компании MosChip.

Для оперативного оформления запроса Вам необходимо перейти по данной ссылке:

<http://moschip.ru/get-element>

Вы можете разместить у нас заказ для любого Вашего проекта, будь то серийное производство или разработка единичного прибора.

В нашем ассортименте представлены ведущие мировые производители активных и пассивных электронных компонентов.

Нашей специализацией является поставка электронной компонентной базы двойного назначения, продукции таких производителей как XILINX, Intel (ex.ALTERA), Vicor, Microchip, Texas Instruments, Analog Devices, Mini-Circuits, Amphenol, Glenair.

Сотрудничество с глобальными дистрибьюторами электронных компонентов, предоставляет возможность заказывать и получать с международных складов практически любой перечень компонентов в оптимальные для Вас сроки.

На всех этапах разработки и производства наши партнеры могут получить квалифицированную поддержку опытных инженеров.

Система менеджмента качества компании отвечает требованиям в соответствии с ГОСТ Р ИСО 9001, ГОСТ РВ 0015-002 и ЭС РД 009

### Офис по работе с юридическими лицами:

105318, г.Москва, ул.Щербаковская д.3, офис 1107, 1118, ДЦ «Щербаковский»

Телефон: +7 495 668-12-70 (многоканальный)

Факс: +7 495 668-12-70 (доб.304)

E-mail: [info@moschip.ru](mailto:info@moschip.ru)

Skype отдела продаж:

moschip.ru

moschip.ru\_4

moschip.ru\_6

moschip.ru\_9